

N-沟道功率 MOS 管/ N-CHANNEL POWER MOSFET

SIF18N20A

●特点：导通电阻低 开关速度快 输入阻抗高 符合RoHS规范

●FEATURES: ■LOW ON-RESISTANCE ■FAST SWITCHING ■HIGH INPUT RESISTANCE ■RoHS COMPLIANT

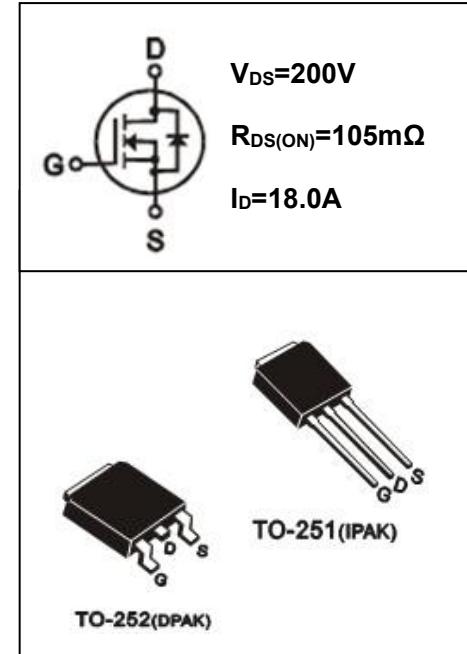
●应用：照明 不间断电源 LED 电视 消费类电器

●APPLICATION: ■LIGHTING ■UNINTERRUPTED POWER SUPPLY ■LED TV ■CONSUMER APPLIANCES

●最大额定值 (Tc=25°C)

●Absolute Maximum Ratings (Tc=25°C) TO-251&252

参数 PARAMETER	符号 SYMBOL	额定值 VALUE	单位 UNIT
漏-源电压 Drain-source Voltage	V _{DS}	200	V
-源电压 gate-source Voltage	V _{GS}	±30	V
漏极电流 Continuous Drain Current TC=25°C	I _D	18	A
漏极电流 Continuous Drain Current TC=100°C	I _D	9	A
最大脉冲电流 Drain Current - Pulsed ①	I _{DM}	72	A
耗散功率 Power Dissipation	P _{tot}	TO-251/252: 50	W
最高结温 Junction Temperature	T _j	150	°C
存储温度 Storage Temperature	T _{STG}	-55-150	°C
单脉冲雪崩能量 Single Pulse Avalanche Energy ②	E _{AS}	320	mJ



●电特性 (Tc=25°C)

●Electronic Characteristics (Tc=25°C)

参数 PARAMETER	符号 SYMBOL	测试条件 TEST CONDITION	最小值 MIN	典型值 TYP	最大值 MAX	单位 UNIT
漏-源击穿电压 Drain-source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	200			V
击穿电压温度系数 Breakdown Voltage Temperature Coefficient	Δ BV _{DSS} / Δ T _j	I _D =250μA, Referenced to 25°C		0.2		V/°C
栅极开启电压 Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =250μA	2.0		4.0	V
漏-源漏电流 Drain-source Leakage Current	I _{DSS}	V _{DS} =200V, V _{GS} =0V, T _j =25°C			1	μA
		V _{DS} =200V, V _{GS} =0V, T _j =125°C			10	μA
跨导 Forward Transconductance	g _{fs}	V _{DS} =10V, I _D =9A ③	6.5			S

●订单信息/ORDERING INFORMATION:

包装形式/PACKING	订货编码/ORDERING CODE	
	普通塑封料/ Normal Package Material	无卤塑封料/Halogen Free
TO-252 条管装 TUBE PACKING	SIF18N20A TO-252-TU	SIF18N20A TO-252-TU-HF
TO-251 条管装/TUBE PACKING	SIF18N20A TO-251-TU	SIF18N20A TO-251-TU-HF

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参数 PARAMETER	符号 SYMBOL	测试条件 TEST CONDITION	最小值 MIN	典型值 TYP	最大值 MAX	单位 UNIT
栅极漏电流 Gate-body Leakage Current ($V_{DS} = 0$)	I_{GSS}	$V_{GS} = \pm 30V$			± 100	nA
漏-源导通电阻 Static Drain-source On Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 9A$ ③		105	150	mΩ
输入电容 Input Capacitance	C_{iss}			1150		pF
输出电容 Output Capacitance	C_{oss}			185		pF
米勒电容 Miller Capacitance	C_{rss}			30		pF
关断延迟 Turn -Off Delay Time	$T_{d(off)}$	$V_{DD} = 100V, I_D = 11A$ $R_G = 3.5\Omega, R_D = 25\Omega$ ③		25		ns
栅极电荷 Total Gate Charge	Q_g			22.5		nC
栅源电荷 Gate-to-Source Charge	Q_{gs}			4.7		nC
栅漏电荷 Gate-to-Drain Charge	Q_{gd}			6.9		nC
二极管正向电流 Continuous Diode Forward Current	I_s				18.0	A
二极管正向压降 Diode Forward Voltage	V_{SD}	$T_j = 25^\circ C, I_s = 18A$ $V_{GS} = 0V$ ③			1.45	V
反向恢复时间 Reverse Recovery Time	t_{rr}				235	ns
反向恢复电荷 Reverse Recovery Charge	Q_{rr}	$T_j = 25^\circ C, I_f = 11A$ $di/dt = 100A/\mu s$ ③		926		uC

●热特性

●Thermal Characteristics

参数 PARAMETER	符号 SYMBOL	最大值 MAX	单位 UNIT
		TO-251/252	
热阻结-壳 Thermal Resistance Junction-case	R_{thJC}	2.5	°C/W
热阻结-环境 Thermal Resistance Junction-ambient	R_{thJA}	62.5	°C/W

注释(Notes):

① 脉冲宽度：以最高结温为限制

Repetitive rating: Pulse width limited by maximum junction temperature

② 初始结温= $25^\circ C$, $V_{DD} = 50V$, $L = 2.0 mH$, $R_G = 25\Omega$, $I_{AS} = 18.0A$

Starting $T_j = 25^\circ C$, $V_{DD} = 50V$, $L = 2.0 mH$, $R_G = 25\Omega$, $I_{AS} = 18.0A$

③ 脉冲测试：脉冲宽度 $\leq 300\mu s$ ，占空比 $\leq 2\%$

Pulse Test : Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$

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● 特性曲线

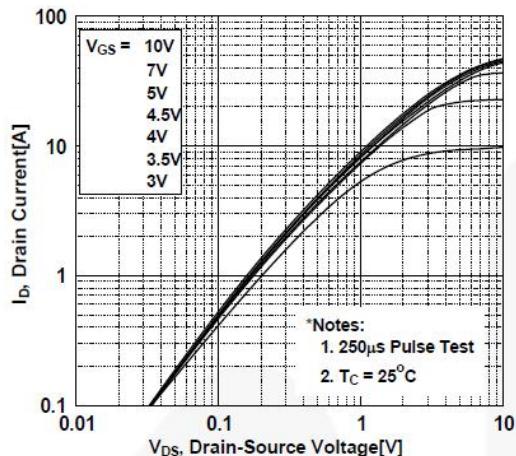


Fig1 Typical Output Characteristics, $T_c = 25^\circ\text{C}$

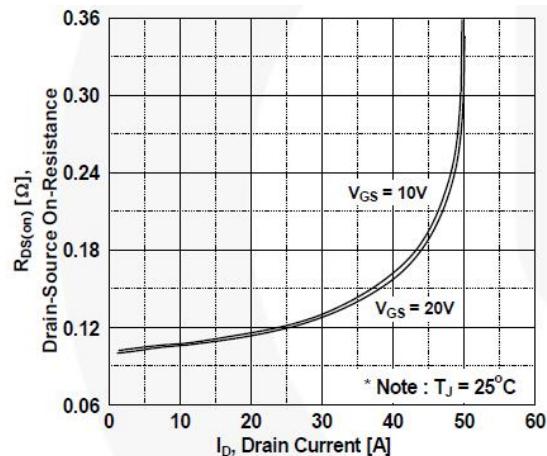


Fig2 On-Resistance Vs.Drain Current and Gate Voltage

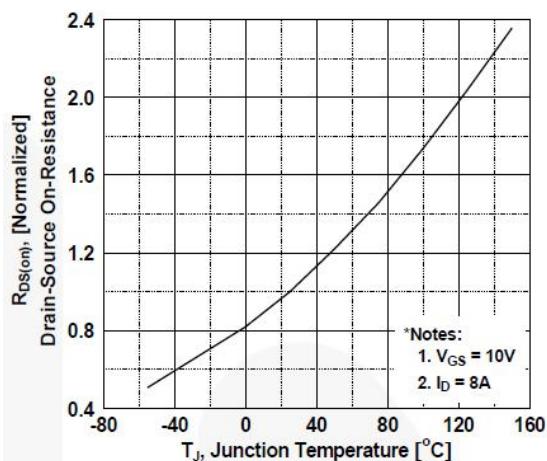


Fig3 Normalized On-Resistance Vs.Temperature

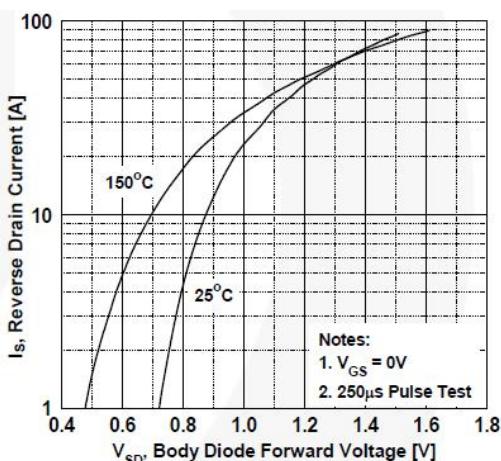


Fig4 Typical Source-Drain Diode Forward Voltage

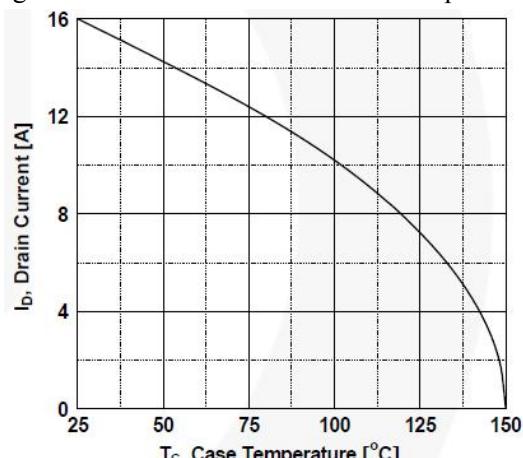


Fig5 Maximum Drain Current Vs.Case Temperature

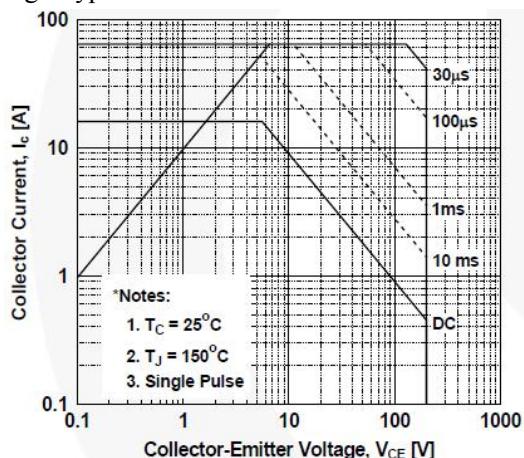


Fig6 Maximum Safe Operating Area

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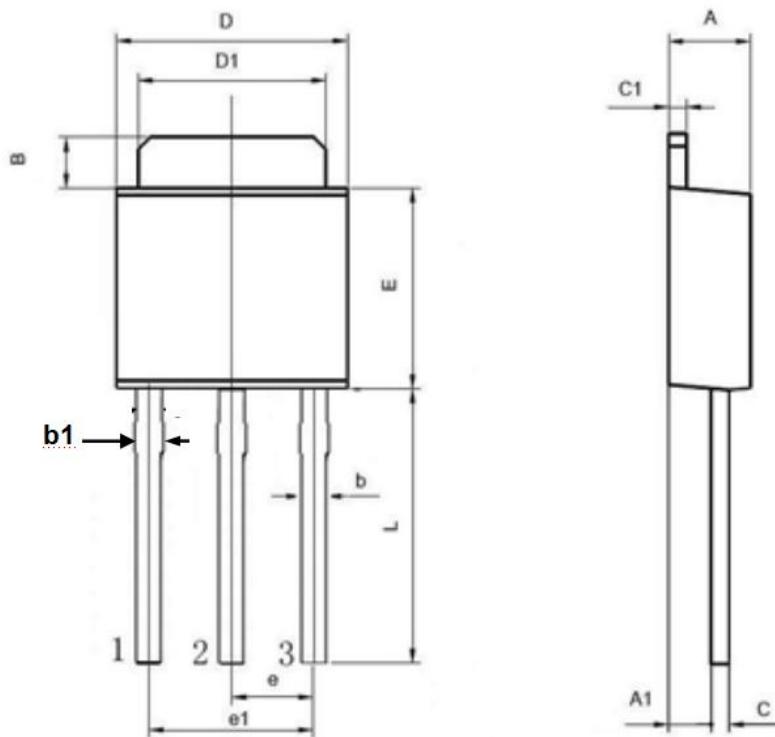
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TO-251 封装机械尺寸

TO-251 (IPAK) MECHANICAL DATA

单位:毫米/UNIT: mm

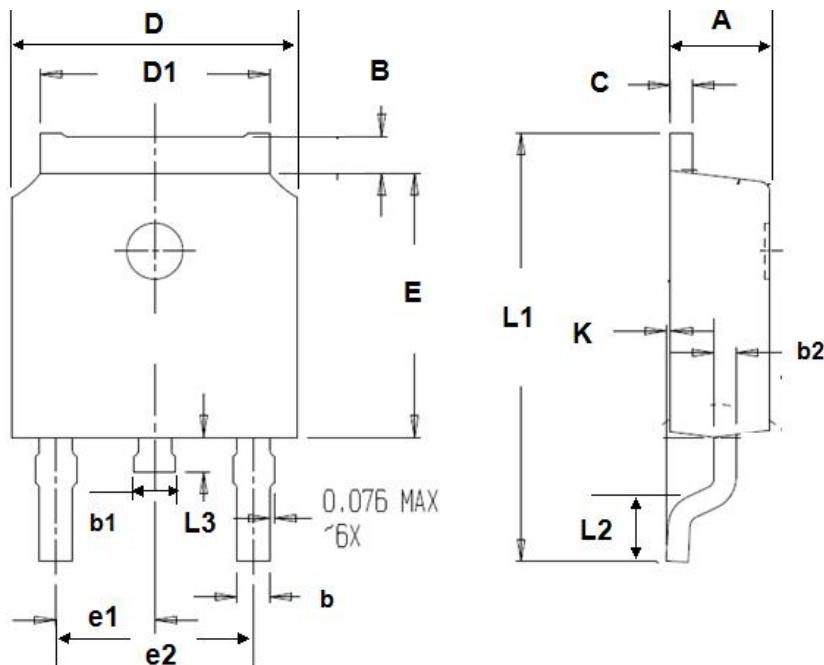
符号/SYMBOL	最小值/min	典型值/nom	最大值/max
A	2.10		2.50
A ₁	0.95		1.30
B	0.80		1.25
b	0.50		0.80
b ₁	0.70		0.90
c	0.45		0.70
c ₁	0.45		0.70
D	6.35		6.80
D ₁	5.10		5.50
E	5.30		6.30
e		2.30	
L	7.00		9.20
R		0.30	[S/L]



TO-252 封装机械尺寸 TO-252 MECHANICAL DATA

单位:毫米/UNIT: mm

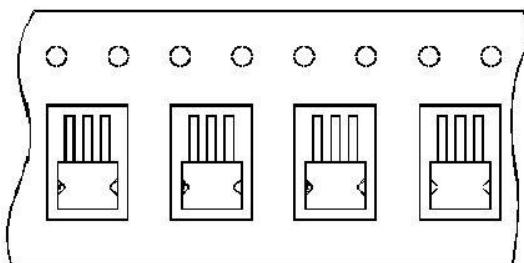
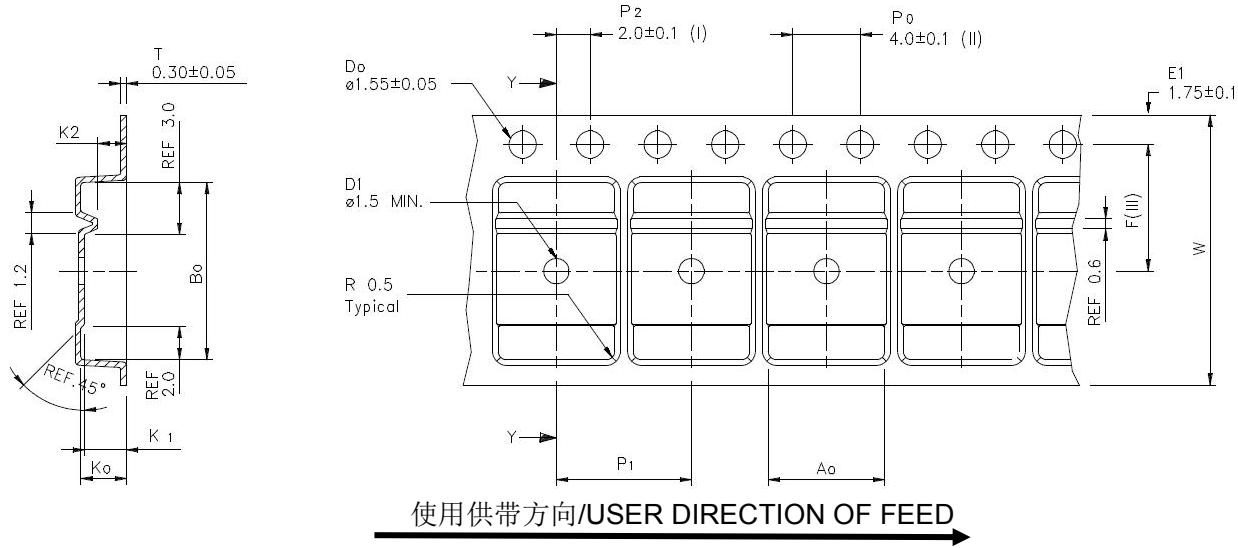
符号 SYMBOL	最小值 min	最大值 max	符号 SYMBOL	最小值 min	最大值 max
A	2.10	2.50	B	0.85	1.25
b	0.50	0.80	b1	0.70	1.10
b2	0.45	0.70	C	0.45	0.70
D	6.30	6.75	D1	5.10	5.50
E	5.30	6.30	e1	2.25	2.35
L1	9.20	10.60	e2	4.45	4.75
L2	0.90	1.75	L3	0.60	1.10
K	0.00	0.23			



TO-252 编带规格尺寸 TO-252 TAPE AND REEL DATA

单位:毫米/UNIT: mm

符号 SYMBOL	最小值 min	典型值 nom	最大值 max	符号 SYMBOL	最小值 min	典型值 nom	最大值 max
A ₀	6.80	6.90	7.00	B ₀	10.40	10.50	10.60
K ₀	2.60	2.70	2.90	K ₁	2.40	2.50	2.60
F	7.40	7.50	7.60	K ₂	1.60	1.70	1.80
W	15.90	16.00	16.10	P ₁	7.90	8.00	8.10



编带器件定位/UNIT ORIENTATION